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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## 3 A LOW Vf Schottky Barrier Rectifier

#### **DESCRIPTION**

In Microsemi's new Powermite3<sup>®</sup> SMT package, these high efficiency ultrafast rectifiers offer the power handing capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies.

In addition to its size advantages, Powermite3® package features include a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly, and a unique locking tab acts as an integral heat sink. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

### ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

| (UNLESS OTHERWISE SPECIFIED)  |  |             |      |  |
|---|--|-------------|------|--|
| Rating  | Symbol   | Value       | Unit |  |
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage  | $egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$ | 40          | V    |  |
| RMS Reverse Voltage   | V <sub>R (RMS)</sub>                                   | 28          | V    |  |
| Average Rectified Output Current  | lo   | 3           | Α    |  |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine wave Superimposed<br>on Rated Load @ T <sub>c</sub> =100 °C | I <sub>FSM</sub>                                       | 50          | А    |  |
| Storage Temperature   | T stg  | -55 to +150 | ºC   |  |
| Operating Temperature   | Тор  | -55 to +125 | ōC   |  |

# THERMAL CHARACTERISTICS (UNLESS OTHERWISE SPECIFIED)

| (3112233 3 11121111132 31 231 122) |         |     |         |  |
|------------------------------------|---------|-----|---------|--|
| Thermal Resistance                 |         |     | _       |  |
| Junction-to Bottom                 | Rja (1) | 2.5 | ºC/Watt |  |
|                                    |         |     |         |  |

(1) When Mounted on PC board with 2 ounce copper pattern.

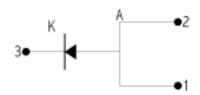


#### **KEY FEATURES**

- High power surface mount package.
- Guard Ring die construction for transient protection.
- Silicon Schottky rectifiers no reverse voltage recovery.
- Internal heat sink locking tabs
- Low forward voltage.
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion equipment
- Low profile-maximum height of 1mm supplied in 16 mm tape reel- 5000 units/ 13" reel.

#### APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies.
- Charge Pump Circuits.
- Reduces reverse recovery loss due to low I<sub>RM</sub>.
- Small foot print 190 X 300 mils 1:1 Actual size



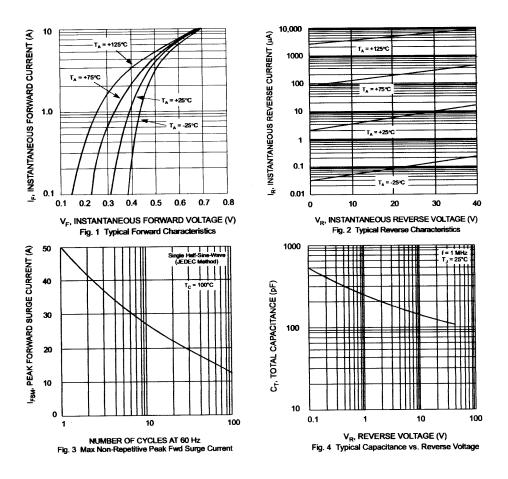
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# 3 A LOW Vf Schottky Barrier Rectifier

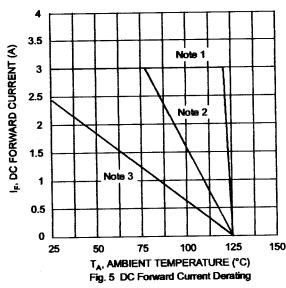
| Dougnator                  | Cymphol         | Conditions  | Min | Tym  | Max     | Llusita |
|----------------------------|-----------------|---|-----|------|---------|---------|
| Parameter                  | Symbol          | Conditions  | Min | Тур. | Max     | Units   |
|                            | 1               | I   |     |      | T = = = | ı       |
| Forward Voltage (Note 1)   |                 | $I_F = 3 \text{ A}, T_j = 25 ^{\circ}\text{C}$  |     | 0.46 | 0.50    |         |
|                            | .,              | $I_F = 3 \text{ A}$ , $T_i = 125 ^{\circ}\text{C}$  |     | 0.40 | 0.44    | V       |
|                            | $V_{Fm}$        | $I_F = 3 \text{ A}$ , $T_j = 125 ^{\circ}\text{C}$<br>$I_F = 6 \text{ A}$ , $T_j = 25 ^{\circ}\text{C}$ |     | 0.57 | 0.61    | V       |
|                            |                 | I <sub>F</sub> = 6 A , T <sub>i</sub> =125 <sup>o</sup> C   |     | 0.54 | 0.58    |         |
| Reverse Break Down Voltage |                 | •   |     |      |         |         |
| (Note 1)                   | $V_{BR}$        | $I_R = 0.5 \text{ mA}$  | 40  |      |         | V       |
| Reverse Current (Note1)    |                 | V <sub>R</sub> = 40V, T <sub>i</sub> = 25 <sup>o</sup> C  |     | 15   | 500     | uА      |
| ,                          | I <sub>rm</sub> | $V_R = 40V, T_j = 100  {}^{\circ}C$   |     | 10   | 20      | mA      |
| Capacitance                | Ст              | V <sub>B</sub> = 4 V; F = 1 MH <sub>z</sub>   |     | 180  |         | pF      |

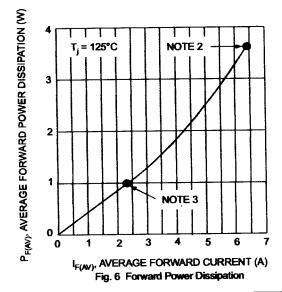
Note: 1 Short duration test pulse used to minimize self – heating effect.





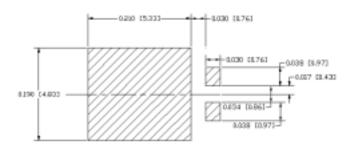
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Notes: 1.  $T_A = T_{SOLDERING\ POINT}$ ,  $R_{\Theta JS} = 3.4^{\circ}$  C/W  $R_{\Theta sa} = 0^{\circ}$  C/W.

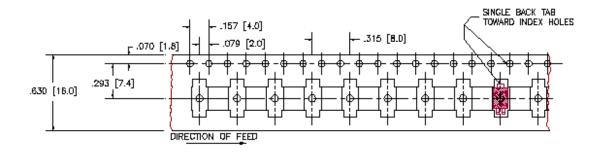
- 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper , double-sided , cathode pad dimensions .075" x 1.0", anode pad dimensions 0.25" x 1.0".  $R_{\Theta JA}$  in range of 20-40° C/W.
- 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta IA}$  in range of 95 115° C/W.



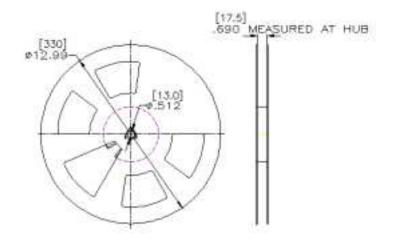


# 3 A LOW Vf Schottky Barrier Rectifier

#### 16 mm TAPE



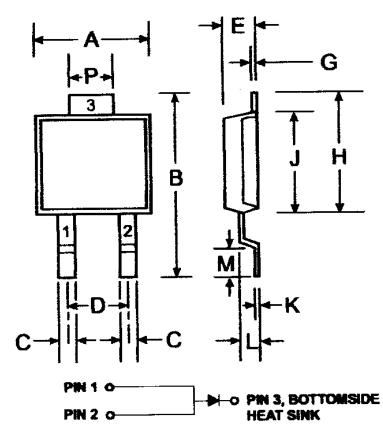
#### 13 INCH REEL



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| POWERMITE®3          |          |      |  |
|----------------------|----------|------|--|
| Dim                  | Min Max  |      |  |
| A                    | 4.03     | 4.09 |  |
| В                    | 6.40     | 6.61 |  |
| С                    | .889 NOM |      |  |
| D                    | 1.83 NOM |      |  |
| Ε                    | 1.10     | 1.14 |  |
| G                    | .178 NOM |      |  |
| н                    | 5.01     | 5.17 |  |
| J                    | 4.37     | 4.43 |  |
| K                    | .178 NOM |      |  |
| L                    | .71      | .77  |  |
| M                    | .36      | .46  |  |
| P                    | 1.73     | 1.83 |  |
| All Dimensions in mm |          |      |  |

Note: Pins 1 & 2 must be electrically connected at the printed circuit board.



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NOTES: